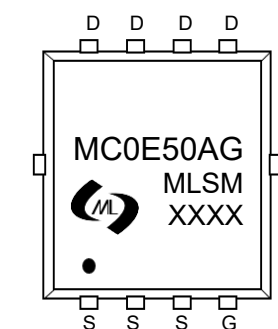


Features

- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Split gate trench MOSFET technology
- Fast switching and soft recovery

Application

- Consumer electronic power supply
- Motor control
- Synchronous-rectification
- Isolated DC/DC convertor



Marking and pin assignment

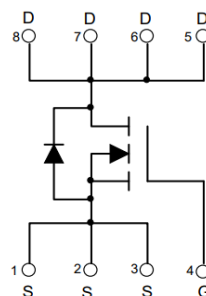
MC0E50AG: Device code
XXXX : Code

Product Summary

V_{DS}	$R_{DS(on)}$ TYP	I_D
40V	8.0mΩ@10V	50A
	10mΩ@4.5V	



PDFN5X6-8L view



Schematic diagram



Pb-Free



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
Common Ratings (TC=25°C Unless Otherwise Noted)			
V_{DS}	Drain-Source Breakdown Voltage	40	V
V_{GS}	Gate-Source Voltage	±20	V
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to 175	°C
E_{AS}	Single pulse avalanche energy ^(Note1)	70	mJ
I_S	Diode Continuous Forward Current	$T_C=25^{\circ}C$ 50	A

Mounted on Large Heat Sink

I_{DM}	Pulse Drain Current Tested	$T_C=25^{\circ}C$ 172	A
I_D	Continuous Drain Current	$T_C=25^{\circ}C$ 50	A
P_D	Maximum Power Dissipation	$T_C=25^{\circ}C$ 33	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	62.5	°C/W

Ordering Information (Example)

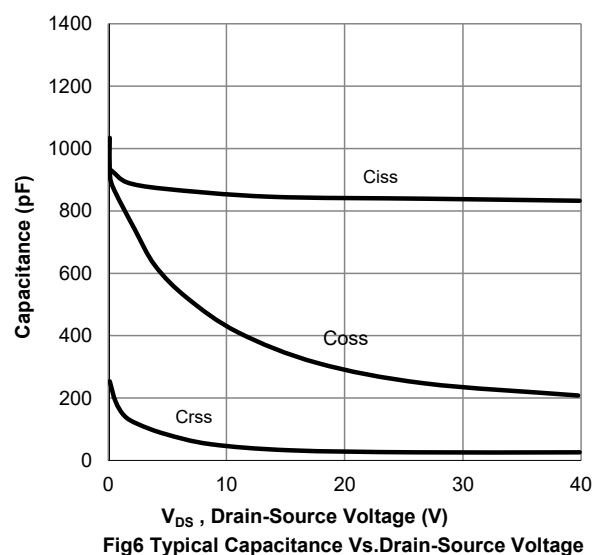
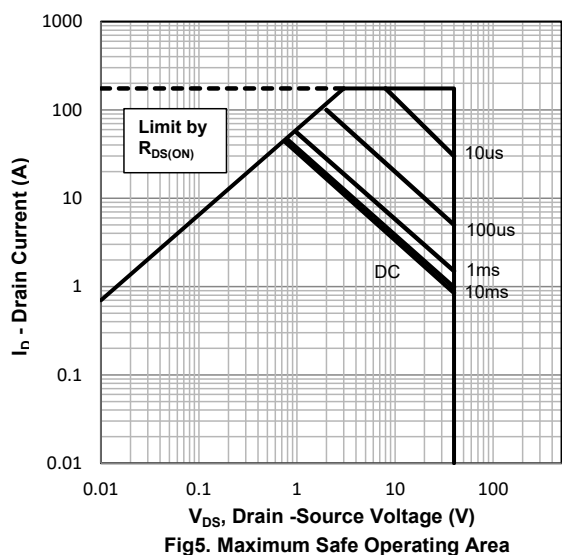
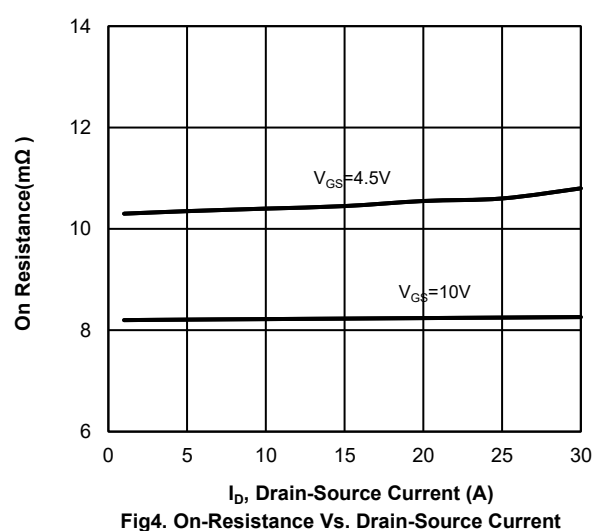
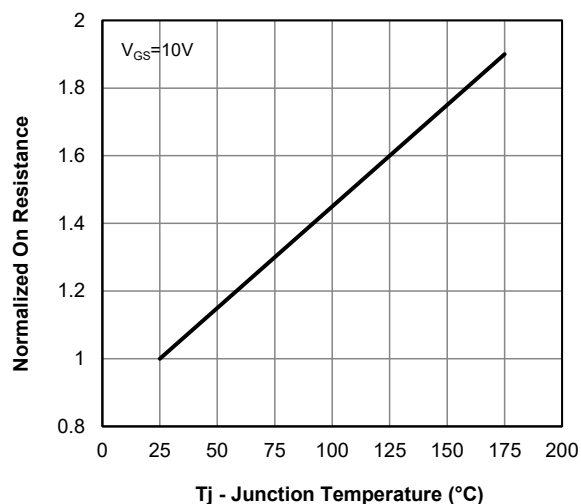
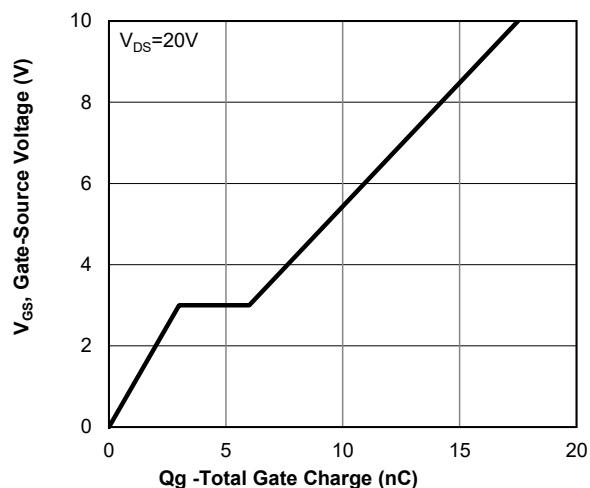
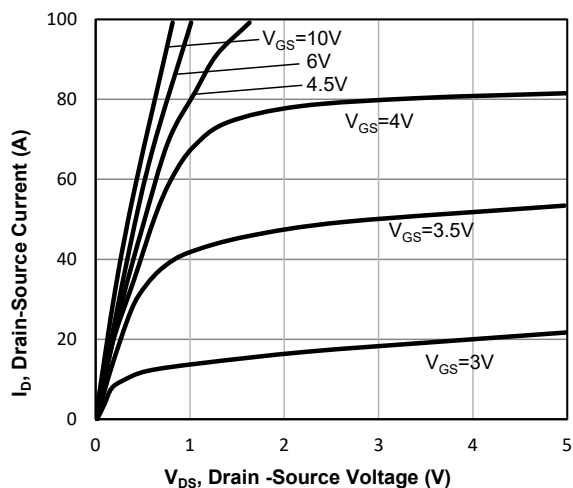
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MC0E50AG	PDFN5X6-8L	MC0E50AG	5,000	10,000	70,000	13"reel

Electrical Characteristics (TJ=25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
BV(BR)DSS	Drain-Source Breakdown Voltage	VGS=0V, ID=250μA	40	--	--	V
IDSS	Zero Gate Voltage Drain Current	VDS=40V, VGS=0V	--	--	1.0	μA
IGSS	Gate-Body Leakage Current	VGS=±20V, VDS=0V	--	--	±100	nA
VGS(th)	Gate Threshold Voltage	VDS=VGS, ID=250μA	1.0	1.7	2.5	V
RDS(on)	Drain-Source On-State Resistance	VGS=10V, ID=20A	--	8.0	11	mΩ
		VGS=4.5V, ID=20A	--	10	14	mΩ
Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
CISS	Input Capacitance	VDS=20V, VGS=0V, f=1MHz	--	831	--	pF
COSS	Output Capacitance		--	318	--	pF
CRSS	Reverse Transfer Capacitance		--	24	--	pF
Switching Characteristics						
Qg	Total Gate Charge	VDS=20V, ID=20A, VGS=10V	--	17.6	--	nC
Qgs	Gate Source Charge		--	3.5	--	nC
Qgd	Gate Drain Charge		--	3.1	--	nC
td(on)	Turn-on Delay Time	VDS=20V, ID=20A, VGS=10V, RG=1.6Ω	--	6	--	nS
tr	Turn-on Rise Time		--	2.8	--	nS
td(off)	Turn-Off Delay Time		--	23	--	nS
tf	Turn-Off Fall Time		--	3	--	nS
Source- Drain Diode Characteristics						
VSD	Forward on voltage	TJ=25°C, IS=20A	--	--	1.2	V

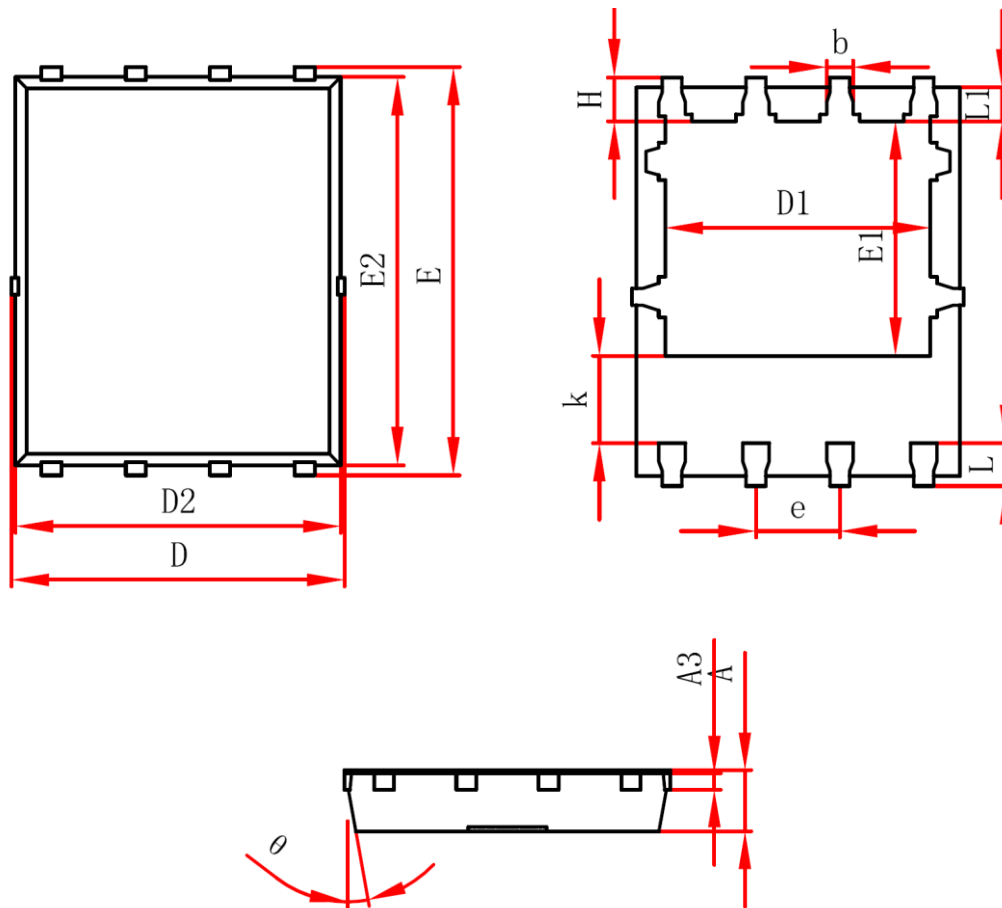
Note:

1、L=0.5mH, V_{DS}=20V, V_{GS}=10V, R_G=25Ω, Starting T_J=25°C

Typical Operating Characteristics



PDFN5X6-8L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions in Inches	
	Min	Max	Min	Max
A	0.950	1.050	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.950	5.050	0.196	0.200
E	5.950	6.050	0.235	0.239
D1	4.026	4.126	0.159	0.163
E1	3.510	3.610	0.139	0.143
D2	4.850	4.950	0.192	0.196
E2	5.700	5.800	0.225	0.229
k	1.190	1.390	0.047	0.055
b	0.300	0.400	0.012	0.016
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
θ	10°	12°	10°	12°